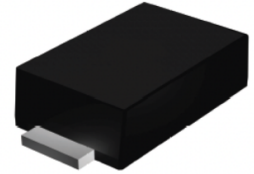


## Features

- Glass passivated junction chip
- Ideal for automated placement
- Super fast recovery time for high efficiency
- Built-in strain relief
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition



SOD-123FL

## Mechanical Data

Case: SOD-123FL  
 Molding compound, UL flammability classification rating 94V-0  
 Moisture sensitivity level: Level 1, per J-STD-020  
 Terminal: Matte tin plated leads, solderable per JESD22-B102  
 Meet JESD 201 class 2 whisker test  
 Polarity: Indicated by cathode band

## Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	GSFU1	GSFU2	GSFU3	GSFU4	GSFU5	Unit
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1					A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load	$I_{FSM}$	30					A
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	- 55 to + 150					$^\circ\text{C}$

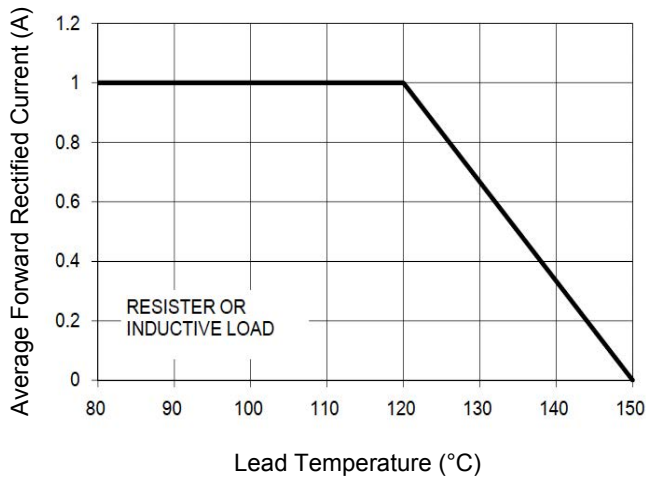
## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Test Conditions	Symbol	GSFU1	GSFU2	GSFU3	GSFU4	GSFU5	Unit
Maximum Instantaneous Forward Voltage <sup>1</sup>	1 A	$V_F$	0.95			1.3	1.7	V
Maximum DC Reverse Current at Rated DC Blocking Voltage	$T_A=25^\circ\text{C}$ $T_A=125^\circ\text{C}$	$I_R$	5.0			100		$\mu\text{A}$
Maximum Reverse Recovery Time <sup>2</sup>	$I_F=0.5\text{A}, I_R=1.0\text{A}, I_{tr}=0.25\text{A}$	$t_{rr}$	35					nS
Typical Junction Capacitance <sup>3</sup>	4.0V, 1MHz	$C_J$	16			18		pF
Typical Thermal Resistance	Junction to Ambient	$R_{\theta JA}$	85					$^\circ\text{C/W}$
	Junction to Lead	$R_{\theta JL}$	35					

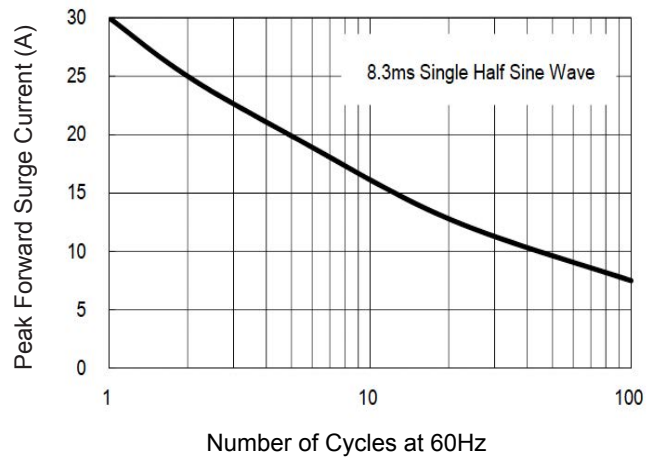
Note:

1. Pulse test with  $PW=300\mu\text{s}$ , 1% duty cycle
2. Reverse recovery test conditions:  $I_F=0.5\text{A}, I_R=1.0\text{A}, I_{RR}=0.25\text{A}$
3. Measured at 1 MHz and applied  $V_R=4.0\text{V}$

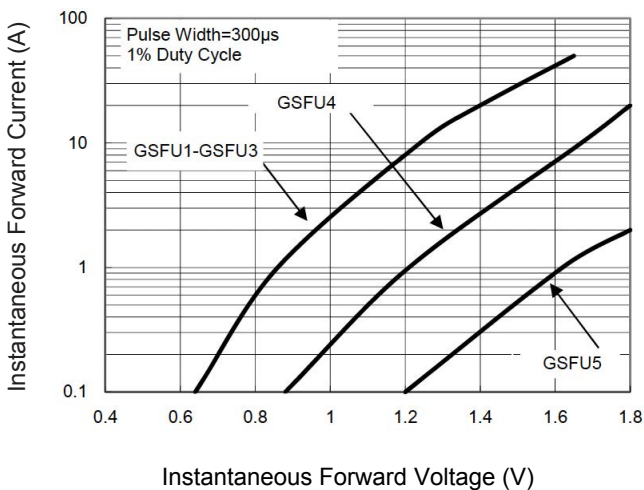
## Ratings and Characteristics Curves ( $T_A=25^\circ\text{C}$ unless otherwise noted)



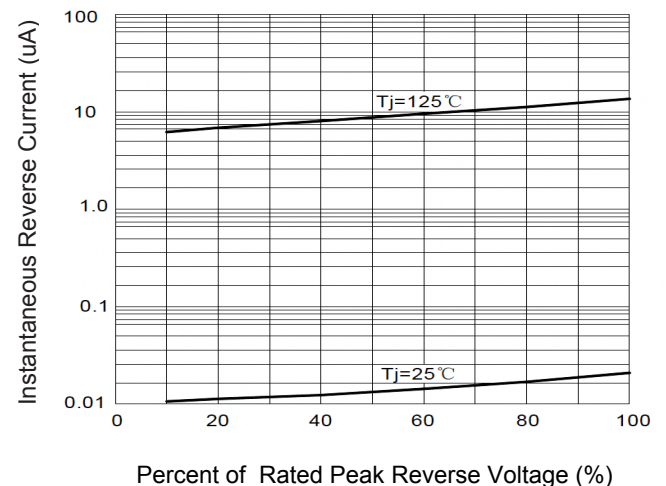
**Figure 1. Maximum Forward Current Derating Curve**



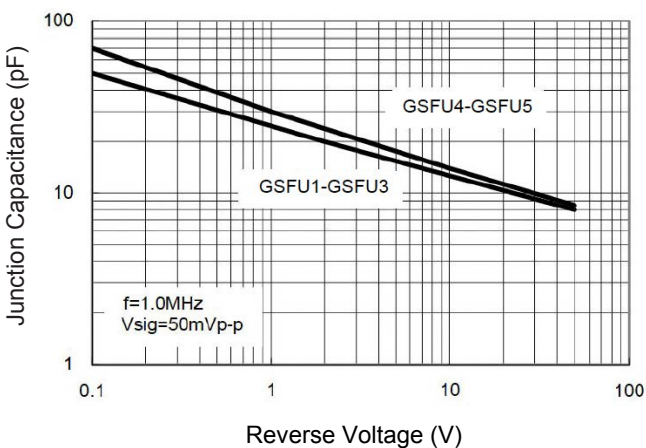
**Figure 2. Maximum Non-Repetitive Peak Forward Surge Current**



**Figure 3. Typical Instantaneous Forward Characteristics**

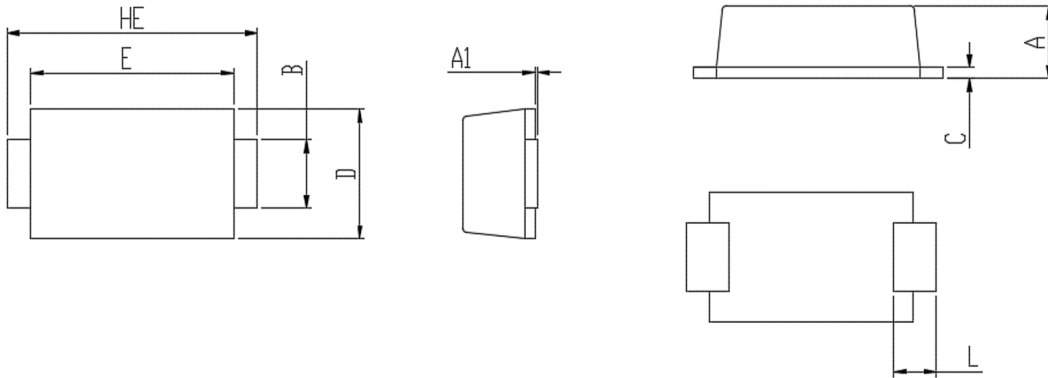


**Figure 4. Typical Reverse Characteristics**



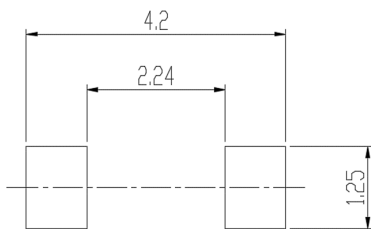
**Figure 5. Typical Junction Capacitance**

## Package Outline Dimensions SOD-123FL



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.080	0.035	0.043
A1	0.000	0.100	0.000	0.004
B	0.850	1.100	0.033	0.043
C	0.100	0.250	0.004	0.010
D	1.700	2.000	0.067	0.079
E	2.900	3.100	0.114	0.122
L	0.430	0.830	0.017	0.033
HE	3.500	3.900	0.138	0.154

## Recommended Pad Layout



Unit: mm

## Order Information

Device	Package	Marking	Carrier	Quantity
GSFU1	SOD-123FL	FU1	Tape & Reel	3,000pcs / Reel
GSFU2	SOD-123FL	FU2	Tape & Reel	3,000pcs / Reel
GSFU3	SOD-123FL	FU3	Tape & Reel	3,000pcs / Reel
GSFU4	SOD-123FL	FU4	Tape & Reel	3,000pcs / Reel
GSFU5	SOD-123FL	FU5	Tape & Reel	3,000pcs / Reel

For more information, please contact us at: [inquiry@goodarksemi.com](mailto:inquiry@goodarksemi.com)